



# PJQ5468A

## 60V N-Channel Enhancement Mode MOSFET

**Voltage**

**60 V**

**Current**

**25 A**

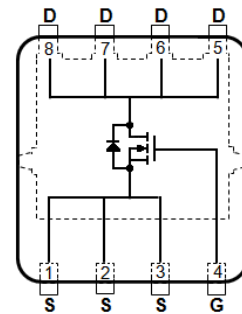
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V, I_D@15A < 34m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V, I_D@10A < 40m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams
- Marking: Q5468A

DFN5060-8L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   |                         | SYMBOL          | LIMIT    | UNITS              |
|---|-------------------------|-----------------|----------|--------------------|
| Drain-Source Voltage                              |                         | $V_{DS}$        | 60       | V                  |
| Gate-Source Voltage                               |                         | $V_{GS}$        | $\pm 20$ | V                  |
| Continuous Drain Current                          | $T_C=25^\circ\text{C}$  | $I_D$           | 25       | A                  |
|   | $T_C=100^\circ\text{C}$ |                 | 16       |                    |
| Pulsed Drain Current <sup>(Note 1)</sup>          | $T_C=25^\circ\text{C}$  | $I_{DM}$        | 100      |                    |
| Power Dissipation                                 | $T_C=25^\circ\text{C}$  | $P_D$           | 40       | W                  |
|   | $T_C=100^\circ\text{C}$ |                 | 16       |                    |
| Continuous Drain Current                          | $T_A=25^\circ\text{C}$  | $I_D$           | 5.5      | A                  |
|   | $T_A=70^\circ\text{C}$  |                 | 4.4      | A                  |
| Power Dissipation                                 | $T_A=25^\circ\text{C}$  | $P_D$           | 2.0      | W                  |
| Power Dissipation                                 | $T_A=70^\circ\text{C}$  |                 | 1.3      |                    |
| Single Pulse Avalanche Energy <sup>(Note 6)</sup> |                         | $E_{AS}$        | 24       | mJ                 |
| Operating Junction and Storage Temperature Range  |                         | $T_J, T_{STG}$  | -55~150  | $^\circ\text{C}$   |
| Typical Thermal Resistance <sup>(Note 4,5)</sup>  | Junction to Case        | $R_{\theta JC}$ | 3.1      | $^\circ\text{C/W}$ |
|   | Junction to Ambient     | $R_{\theta JA}$ | 62.5     |                    |

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION   | MIN. | TYP. | MAX.      | UNITS      |
|---|--------------|--|------|------|-----------|------------|
| <b>Static</b>   |              |  |      |      |           |            |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$  | 60   | -    | -         | V          |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$                                    | 1.0  | 1.83 | 2.5       | V          |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=10V, I_D=15A$  | -    | 28   | 34        | m $\Omega$ |
|   |              | $V_{GS}=4.5V, I_D=10A$   | -    | 33   | 40        |            |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=60V, V_{GS}=0V$  | -    | -    | 1.0       | $\mu A$    |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$                                      | -    | -    | $\pm 100$ | nA         |
| <b>Dynamic</b> (Note 7)                               |              |  |      |      |           |            |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=30V, I_D=20A,$<br>$V_{GS}=10V$ (Note 1,2)                | -    | 20   | -         | nC         |
| Gate-Source Charge                                    | $Q_{gs}$     |  | -    | 3.8  | -         |            |
| Gate-Drain Charge                                     | $Q_{gd}$     |  | -    | 3.9  | -         |            |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=25V, V_{GS}=0V,$<br>$f=1.0\text{MHz}$                    | -    | 1173 | -         | pF         |
| Output Capacitance                                    | $C_{oss}$    |  | -    | 63   | -         |            |
| Reverse Transfer Capacitance                          | $C_{rss}$    |  | -    | 44   | -         |            |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=15V, I_D=1A,$<br>$V_{GS}=10V, R_G=6\Omega$<br>(Note 1,2) | -    | 7.1  | -         | ns         |
| Turn-On Rise Time                                     | $t_r$        |  | -    | 25   | -         |            |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |  | -    | 31   | -         |            |
| Turn-Off Fall Time                                    | $t_f$        |  | -    | 20   | -         |            |
| <b>Drain-Source Diode</b>                             |              |  |      |      |           |            |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---  | -    | -    | 25        | A          |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=1A, V_{GS}=0V$  | -    | 0.72 | 1.2       | V          |

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_J(\text{MAX})=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited.
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz. square pad of copper.
6. The test condition is  $L=0.1\text{mH}$ ,  $I_{AS}=22A$ ,  $V_{DD}=25V$ ,  $V_{GS}=10V$
7. Guaranteed by design, not subject to production testing.



# PJQ5468A

## TYPICAL CHARACTERISTIC CURVES

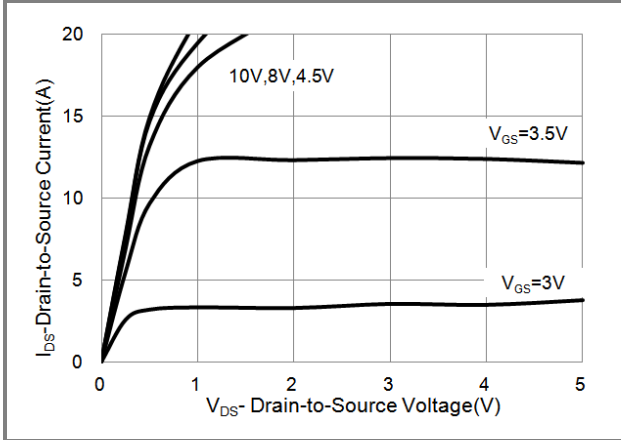


Fig.1 Output Characteristics

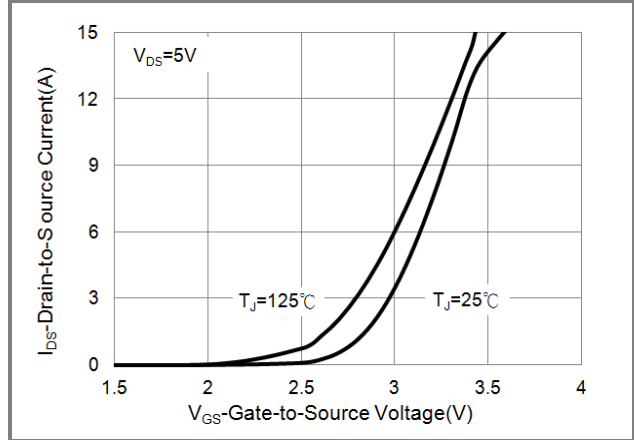


Fig.2 Transfer Characteristics

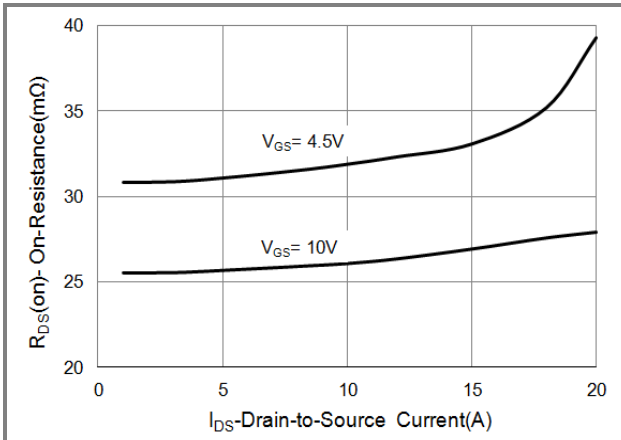


Fig.3 On-Resistance vs. Drain Current

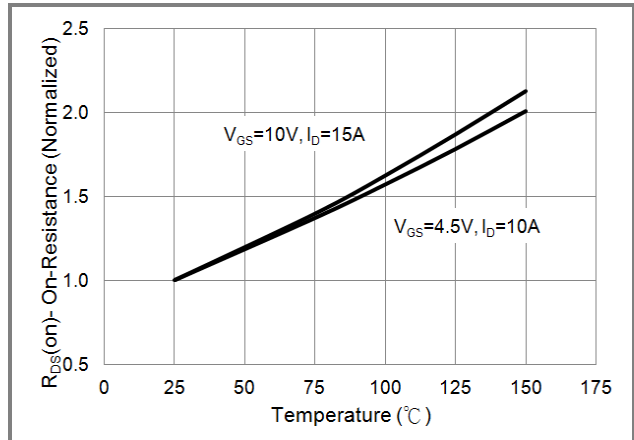


Fig.4 On-Resistance vs. Junction temperature

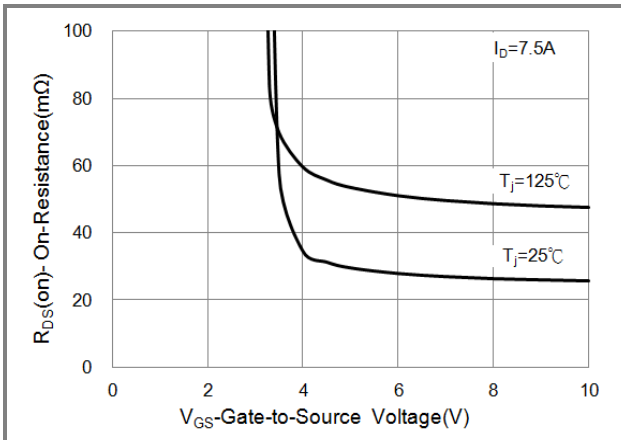


Fig.5 On-Resistance Variation with VGS.

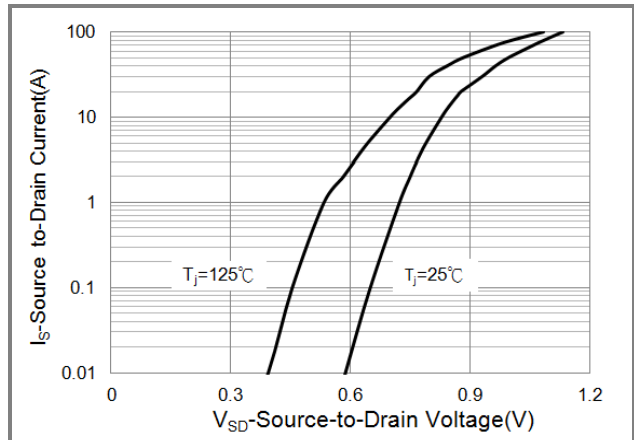


Fig.6 Source-Drain Diode Forward Voltage



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## TYPICAL CHARACTERISTIC CURVES

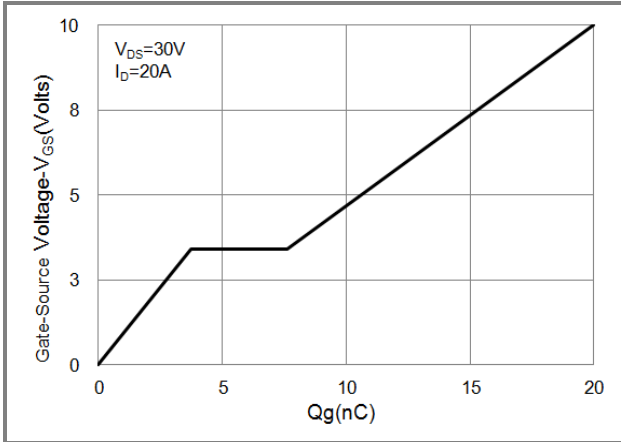


Fig.7 Gate-Charge Characteristics

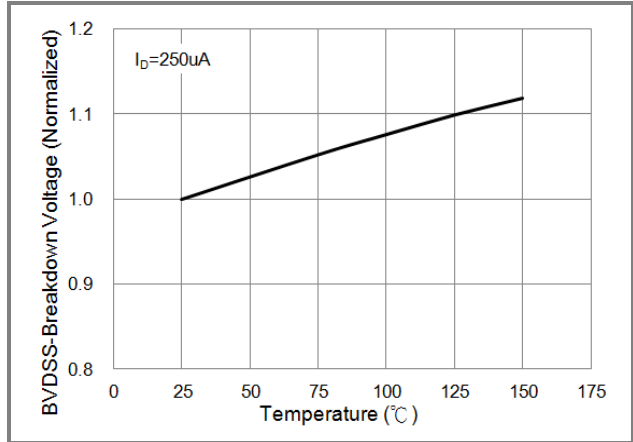


Fig.8 Breakdown Voltage Variation vs. Temperature

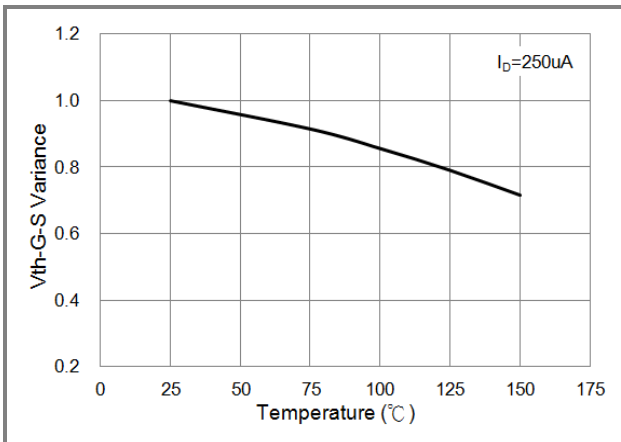


Fig.9 Threshold Voltage Variation with Temperature

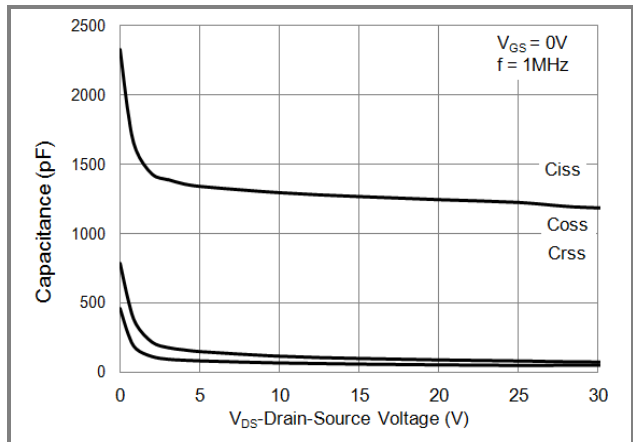


Fig.10 Capacitance vs. Drain-Source Voltage

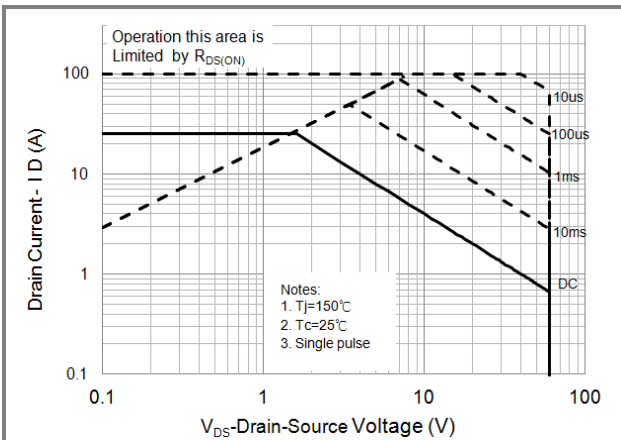


Fig.11 Maximum Safe Operating Area



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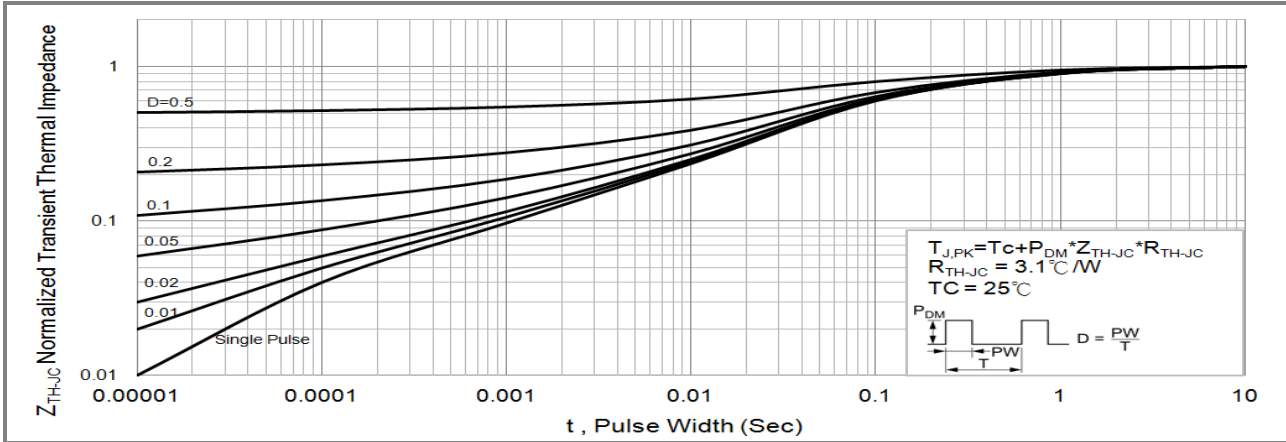


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

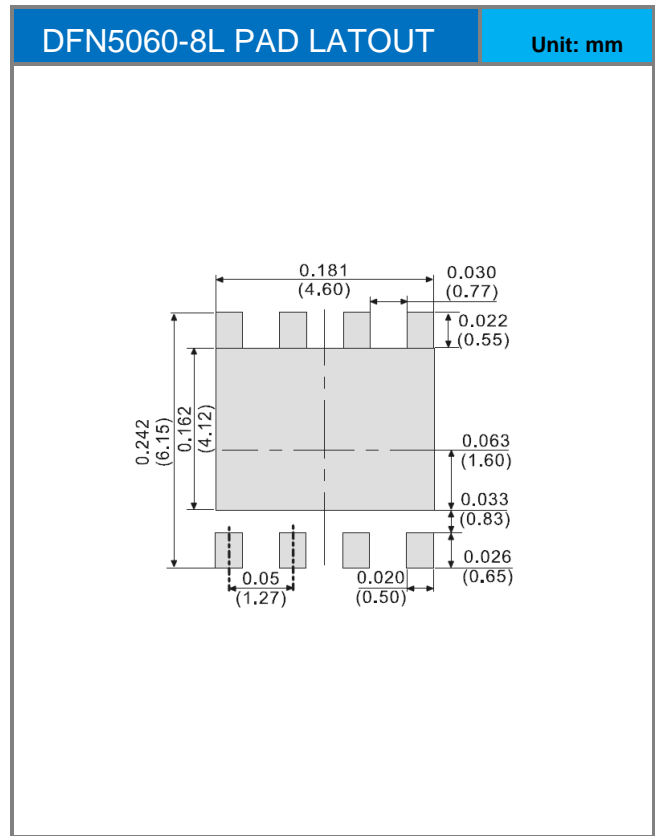
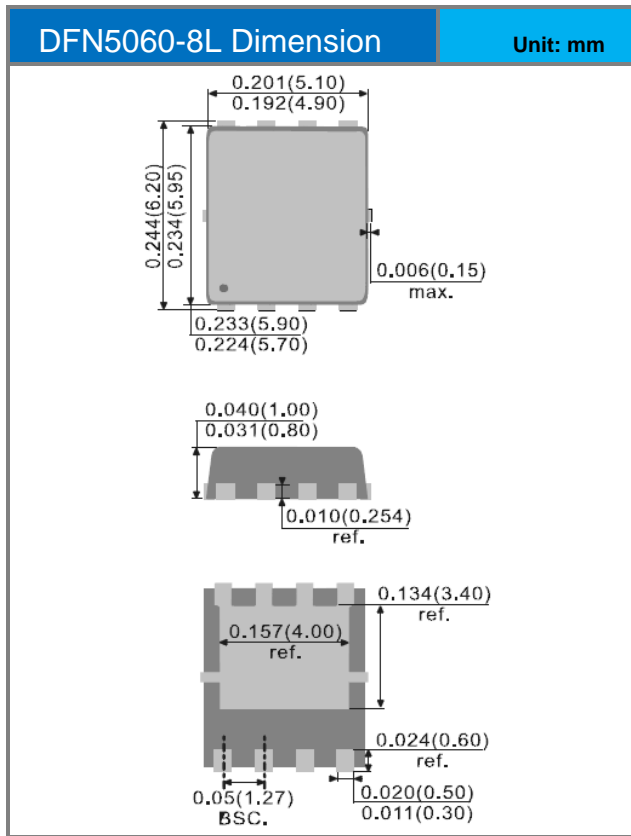


# PJQ5468A

## PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type       | Marking | Version      |
|----------------------|--------------|--------------------|---------|--------------|
| PJQ5468A_R2_00001    | DFN5060-8L   | 3000pcs / 13" reel | Q5468A  | Halogen free |

## Packaging Information & Mounting Pad Layout





## PJQ5468A

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